NSN 5962-01-341-5884

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View Online at https://aerobasegroup.com/nsn/5962-01-341-5884 **Body Length:** 1.060 inches **Body Width:** 0.310 inches **Body Height:** 0.200 inches **Maximum Power Dissipation Rating:** 320.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Ultraviolet erasable and burn in and asynchronous and hermetically sealed and programmed **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 10 input **Current Rating Per Characteristic:** 25.00 milliamperes average forward current averaged over a full 60-hz cycle not applicable **Terminal Surface Treatment:** Solder **Product Name:** Tre rotating priorities, odd bank **Voltage Rating And Type Per Characteristic:** 7.0 volts power source **Capitance Rating Per Characteristic:** 12.00 input picofarads **Time Rating Per Chacteristic:** 50.00 nanoseconds input to output access **Memory Device Type:** Pal **Test Data Document:**

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

20 printed circuit

Shelf Life:

N/a

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Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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